| L Number | Hits   | Search Text   | DB                 | Time stamp       |
|----------|--------|---|--------------------|------------------|
| 1        | 258157 | isolation or STI  | USPAT;             | 2004/07/14 11:48 |
| '        |        |   | US-PGPUB           |                  |
| 2        | 16492  | epitaxial with semiconductor  | USPAT;             | 2004/07/14 11:55 |
| -        |        |   | US-PGPUB           |                  |
| 3        | 263    | (dop\$3 or implant\$3) with gas with in-situ  | USPAT;             | 2004/07/14 12:04 |
|          |        |   | US-PGPUB           |                  |
| 5        | 0      | (isolation or STI) and ((epitaxial with semiconductor) with   | USPAT;             | 2004/07/14 11:50 |
|          |        | ((dop\$3 or implant\$3) with gas with in-situ))   | US-PGPUB           |                  |
| 4        | 3      | (epitaxial with semiconductor) with ((dop\$3 or implant\$3) with  | USPAT;             | 2004/07/14 11:53 |
| 1        |        | gas with in-situ)   | US-PGPUB           |                  |
| 6        | 5      | (epitaxial with semiconductor) same ((dop\$3 or implant\$3) with  | USPAT;             | 2004/07/14 11:53 |
|          |        | gas with in-situ)   | US-PGPUB           |                  |
| 7        | 2      | (isolation or STI) and ((epitaxial with semiconductor) same   | USPAT;             | 2004/07/14 11:53 |
|          |        | ((dop\$3 or implant\$3) with gas with in-situ))   | US-PGPUB           |                  |
| 8        | 24649  | epitaxial with (semiconductor or polysiliocn or silicon)  | USPAT;             | 2004/07/14 11:55 |
|          |        |   | US-PGPUB           |                  |
| 9        | 3      | (epitaxial with semiconductor) with ((dop\$3 or implant\$3) with  | USPAT;             | 2004/07/14 11:55 |
|          |        | gas with in-situ)   | US-PGPUB           |                  |
| 11       | 16492  | (epitaxial with semiconductor) with (epitaxial with   | USPAT;             | 2004/07/14 11:56 |
|          |        | (semiconductor or polysiliocn or silicon))  | US-PGPUB           |                  |
| 12       | 6094   | (isolation or STI) and ((epitaxial with semiconductor) with   | USPAT;             | 2004/07/14 11:56 |
|          |        | (epitaxial with (semiconductor or polysiliocn or silicon)))   | US-PGPUB           |                  |
| 13       | 357078 | @ad>20020511 or @rlad>20020511  | USPAT;             | 2004/07/14 11:56 |
|          |        |   | US-PGPUB           |                  |
| 14       | 5290   | ((isolation or STI) and ((epitaxial with semiconductor) with  | USPAT;             | 2004/07/14 11:56 |
|          |        | (epitaxial with (semiconductor or polysiliocn or silicon)))) not  | US-PGPUB           |                  |
|          |        | (@ad>20020511 or @rlad>20020511)  |                    |                  |
| 15       | 12     | ((dop\$3 or implant\$3) with gas with in-situ) with (epitaxial with   | USPAT;             | 2004/07/14 11:56 |
|          |        | (semiconductor or polysiliocn or silicon))  | US-PGPUB           |                  |
| 16       | 11     | (((dop\$3 or implant\$3) with gas with in-situ) with (epitaxial with  | USPAT;             | 2004/07/14 11:56 |
|          |        | (semiconductor or polysiliocn or silicon))) not (@ad>20020511   | US-PGPUB           |                  |
|          | _      | or @rlad>20020511)  | LICDAT             | 0004/07/44 44:57 |
| 17       | 5      | (isolation or STI) and ((((dop\$3 or implant\$3) with gas with  | USPAT;             | 2004/07/14 11:57 |
|          |        | in-situ) with (epitaxial with (semiconductor or polysiliocn or  | US-PGPUB           |                  |
|          | 2252   | silicon))) not (@ad>20020511 or @rlad>20020511))  | LICDAT.            | 2004/07/44 42:04 |
| 18       | 2859   | (dop\$3 or implant\$3) with in-situ   | USPAT;             | 2004/07/14 12:04 |
| 40       | 444    | ( the - i - t i the - ( i d) d i the i the i the  | US-PGPUB           | 2004/07/14 12:04 |
| 19       | 111    | (epitaxial with (semiconductor or polysiliocn or silicon)) with   | USPAT;<br>US-PGPUB | 2004/07/14 12:04 |
| 20       | 50     | ((dop\$3 or implant\$3) with in-situ) (isolation or STI) and ((epitaxial with (semiconductor or                                 | USPAT;             | 2004/07/14 12:05 |
| 20       | 58     | (Isolation of 511) and ((epitaxial with (semiconductor of   | USPAT;<br>US-PGPUB | 2004/07/14 12.05 |
| 24       | 40     | polysiliocn or silicon)) with ((dop\$3 or implant\$3) with in-situ)) ((isolation or STI) and ((epitaxial with (semiconductor or | USPAT;             | 2004/07/14 12:05 |
| 21       | 48     | polysiliocn or silicon)) with ((dop\$3 or implant\$3) with in-situ)))   | US-PGPUB           | 2004/07/14 12.05 |
|          |        | not (@ad>20020511 or @rlad>20020511)  | 03-70706           |                  |
|          |        | not (@ad>20020511 of @flad>20020511)  | L                  |                  |